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System Basis Chip with CAN FD, LDO Regulator and Wake-up Comparator

NCV7451

The system basis chip (SBC) NCV7451 integrates +5 V / 250 mA LDO regulator with a high-speed CAN FD transceiver and local wake-up comparator, directly controlled by dedicated pins.

Features

- 5 V $\pm 2\%$ / 250 mA LDO
 - ◆ Current Limitation with Fold-back
 - ◆ Output Voltage Monitoring
- One High-Speed CAN FD Transceiver
 - ◆ Compliant to ISO11898-2:2016
 - ◆ CAN FD Timing Specified up to 5 Mbps
 - ◆ Current Limitation, Reverse Current Protected
 - ◆ TxDC Timeout
- Local Wake-up Comparator
 - ◆ Integrated Pull-up / Pull-down Current Source
- Very Low Current Quiescent Consumption
- Window Watchdog
- Direct Control
- Thermal Shutdown Protection
- AEC-Q100 Qualified and PPAP Capable
- Wettable Flank Package for Enhanced Optical Inspection
- This is a Pb-Free Device

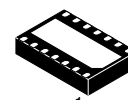
Typical Applications

- Automotive
- Industrial Networks



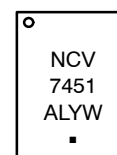
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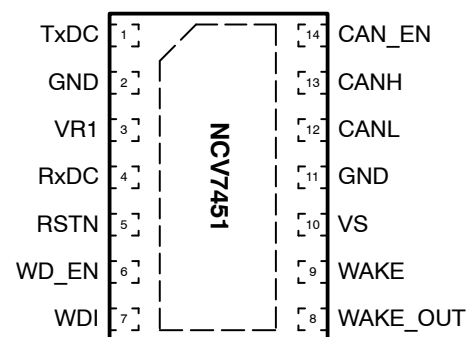
DFNW14 4.5x3, 0.65P
CASE 507AC

MARKING DIAGRAM



NCV7451 = Specific Device Code
A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
▪ = Pb-Free Package

PIN CONNECTIONS



ORDERING INFORMATION

Device	Package	Shipping [†]
NCV7451MW0R2G	DFNW14 (Pb-Free)	5000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

NCV7451

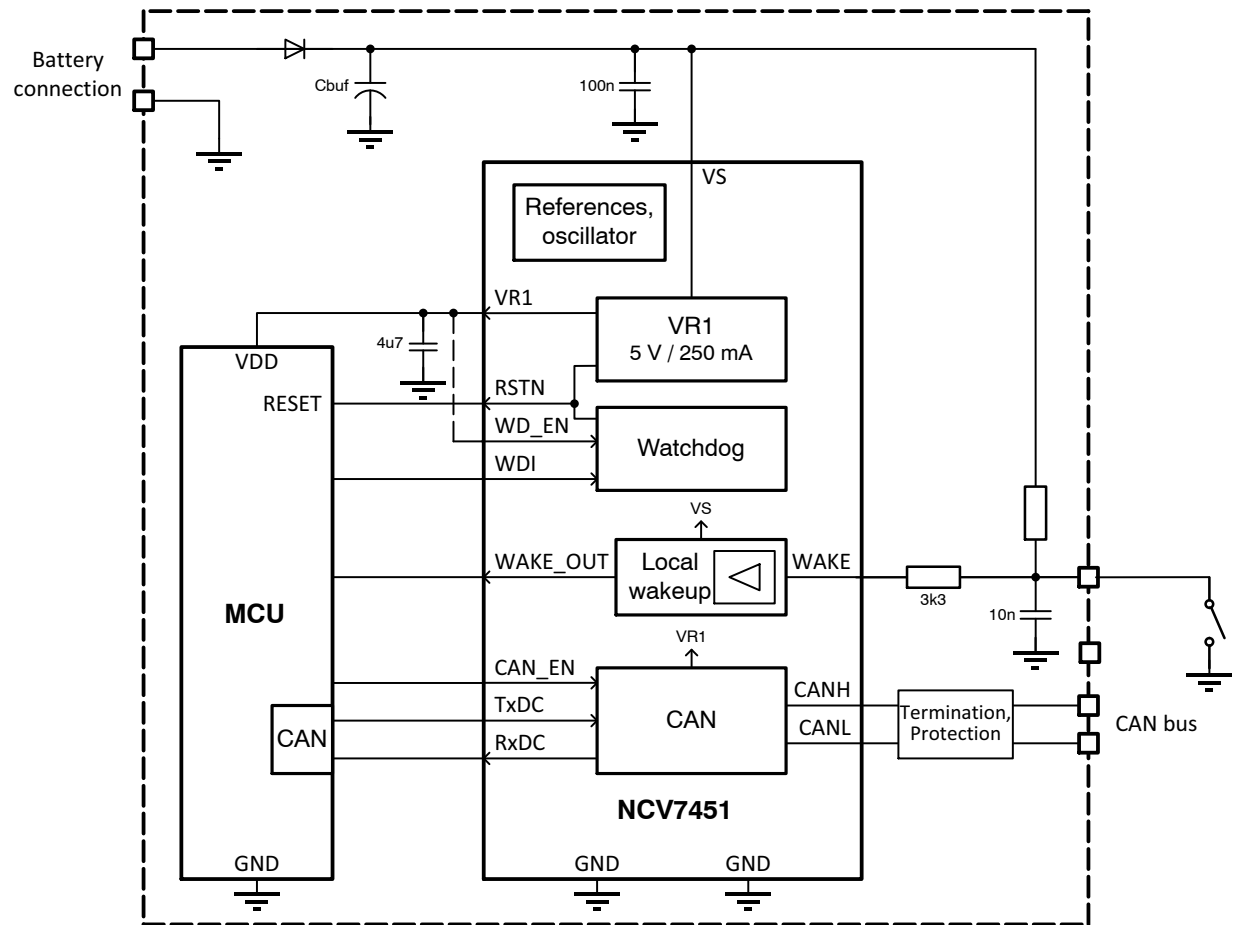


Figure 1. Simplified Application Diagram

NCV7451

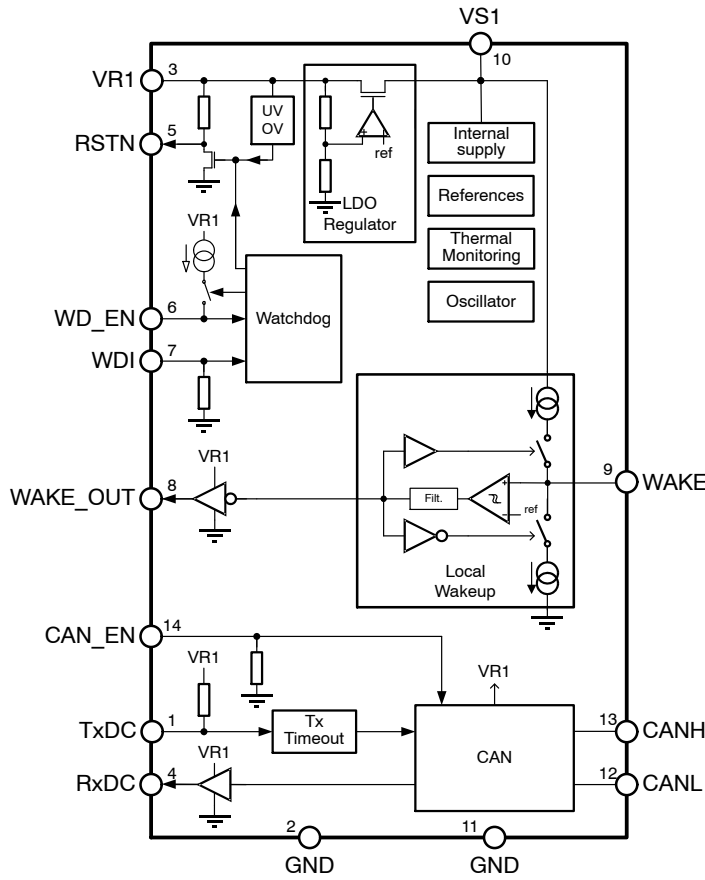


Figure 2. Block Diagram

PIN FUNCTION DESCRIPTION

Pin No.	Pin Name	Pin Type (LV = Low Voltage; HV = High Voltage)	Description
1	TxDC	LV digital input; internal pull-up	CAN transmitter data input
2	GND	Ground connection	Ground supply (all GND pins have to be connected externally)
3	VR1	LV supply output	Output of the 5 V / 250 mA low-drop regulator
4	RxDC	LV digital output; push-pull	CAN receiver data output
5	RSTN	LV digital output; open drain; internal pull-up	Reset signal to the MCU
6	WD_EN	LV digital input; internal pull-up current	Watchdog enable input
7	WDI	LV digital input; internal pull-down	Watchdog trigger input
8	WAKE_OUT	LV digital output	WAKE pin output (inverted WAKE level)
9	WAKE	HV input; pull-up/-down current	WAKE pin
10	VS	HV supply input	Main supply input
11	GND	Ground connection	Ground supply (all GND pins have to be connected externally)
12	CANL	CAN bus interface	CANL line of the CAN bus
13	CANH	CAN bus interface	CANH line of the CAN bus
14	CAN_EN	LV digital input; internal pull-down	CAN transceiver enable input
	EP	Exposed pad	Substrate (has to be connected to all GND pins externally)

MAXIMUM RATINGS

Symbol	Rating		Min	Max	Unit
VS	DC Power Supply Voltage (Note 1)		− 0.3	+40	V
VR1	LDO Supply pin output voltage		− 0.3	6 or VS+0.3 (whichever is lower)	V
VdigIO	DC voltage on digital pins (CAN_EN, WD_EN, WDI, RSTN, RxDC, TxDC, WAKE_OUT)		− 0.3	VR1+0.3	V
WAKE	DC WAKE pin Input Voltage		− 40	+40	V
CANH, CANL	DC voltage on pin CANH and CANL		− 40	+40	V
Vdiff	Differential DC voltage between any two pins (incl. CANH and CANL)		− 40	+40	V
V_ESDHBM	ESD capability, Device HBM, according to AEC-Q100-002 (EIA/JESD22-A114); (Note 2)	Pins VS, CANH, CANL, WAKE	− 8	+8	kV
		Other pins	− 4	+4	
V_ESDMM	ESD capability; MM, according to AEC-Q100-003 (EIA/JESD22-A115); all pins		−200	+200	V
V_ESDCDM	ESD capability; CDM, according to AEC-Q100-011 (EIA/JESD22-C101); all pins		− 750	+750	V
V_ESDIEC	ESD capability; System HBM, according to IEC61000-4-2; pins VS, CANH, CANL, WAKE; (Note 3)		−6	+6	kV
V_SCHAF	Voltage transients, Test pulses According to ISO7637 – 2, Class D; pins VS, CANH, CANL, WAKE	Test pulse 1	− 100	−	V
		Test pulse 2a	−	+75	V
		Test pulse 3a	− 150	−	V
		Test pulse 3b	−	+100	V
Tj	Junction Temperature Range		− 40	+150	°C
Tstg	Storage Temperature Range		− 55	+150	°C
Tsld	Peak Soldering Temperature (Note 4)		−	260	°C
MSL	Moisture Sensitivity Level		1		−

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Refer to ELECTRICAL CHARACTERISTICS, RECOMMENDED OPERATING RANGES and/or APPLICATION INFORMATION for Safe Operating parameters.
2. Equivalent to discharging a 100 pF capacitor through a 1.5 kΩ resistor
3. Equivalent to discharging a 150 pF capacitor through a 330 Ω resistor; WAKE pin stressed through an external series resistor of 3.3 kΩ and with 10 nF capacitor on the module input, VS pin decoupled with 100 nF.
4. For information, please refer to our Soldering and Mounting Techniques Reference Manual, SOLDERRM/D

THERMAL CHARACTERISTICS

Symbol	Rating	Value	Unit
RθJA	Thermal Characteristics, Thermal Resistance, Junction-to-Air (Note 5) Thermal Reference, Junction-to-Air (Note 6)	77 52	°C/W
RψJC	Thermal Characteristics, Thermal Resistance, Junction-to-Case	7	°C/W

5. Value based on test board according to JESD51-3 standard, signal layer with 10% trace coverage.

6. Value based on test board according to JESD51-7 standard, signal layers with 20% trace coverage, inner planes with 90% coverage.

RECOMMENDED OPERATING RANGES

Symbol	Rating	Min	Max	Unit
VS	Functional supply voltage	5.0	28	V
	Supply voltage for valid parameter specification	6.0	18	V
VR1	VR1 regulator output voltage	4.9	5.1	V
I(VR1)	VR1 regulator output current (including CAN transceiver consumption)	0	250	mA
VdigIO	Digital inputs/outputs voltage	0	VR1	V
WAKE	WAKE input voltage	0	VS	V
CANH, CANL	CAN bus pins voltage	-40	40	V
T _J	Junction Temperature	-40	150	°C
T _A	Ambient Temperature	-40	125	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

ELECTRICAL CHARACTERISTICS

6 V ≤ VS ≤ 18 V; -40°C ≤ T_J ≤ 150°C; 4.75 V ≤ VR1 ≤ 5.25 V; R_{LT} = 60 Ω, C_{LT} = 100 pF, C_{ST} not used, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
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VS SUPPLY

VS_PORH	VS POR threshold	VS rising	3.4	–	4.1	V
VS_PORL	VS POR threshold	VS falling	2.0	–	3.5	V
I _{s_off}	VS consumption, low-power	VS = 14 V, VR1 on (not loaded), WAKE floating, CAN bus recessive, CAN_EN = Low, WD_EN = Low, T _J ≤ 85°C	–	28	35	μA
I _{s_act}	VS consumption, active	VS = 14 V, VR1 on (loaded by 100 mA, not included in I _{s_act}), WAKE floating, CAN bus recessive, CAN_EN = High, WD_EN = High, TxDC = High	–	3.7	5.0	mA

VR1 VOLTAGE REGULATOR

V_VR1	Regulator output voltage	0 mA ≤ I(VR1) ≤ 250 mA (including internal CAN consumption), 6 V ≤ VS ≤ 28 V	4.9	5.0	5.1	V
Ilim_VR1	Regulator current limitation	Maximum VR1 overload current, VR1 > RES_VR1	250	–	650	mA
Ishort_VR1	Regulator short current	Maximum VR1 short current, VR1 < RES_VR1	125	1/2 x Ilim_VR1	325	mA
Vdrop_VR1	Dropout Voltage	I(VR1) = 100 mA, VS = 5 V	–	0.2	0.4	V
		I(VR1) = 100 mA, VS = 4.5 V	–	0.2	0.5	
		I(VR1) = 50 mA, VS = 4.5 V	–	0.1	0.4	
Loadreg_VR1	Load Regulation	1 mA ≤ I(VR1) ≤ 100 mA	-50	–	50	mV
Linreg_VR1	Line Regulation	I(VR1) ≤ 100 mA	-40	–	40	mV
Cload_VR1	VR1 load capacity	ESR < 200 mΩ, ceramic capacitor recommended	1.0	4.7	–	μF
RES_VR1	VR1 Reset threshold	VR1 voltage decreasing	4.3	4.5	4.7	V
RES_hyst_VR1	VR1 Reset threshold hysteresis		0.05	0.1	0.2	V
tfilt_RES_VR1	VR1 undervoltage filter time		–	15	–	μs
OV_VR1	VR1 overvoltage threshold	VR1 voltage increasing / decreasing	5.5	–	6.0	V
OV_hyst_VR1	VR1 overvoltage threshold hysteresis		–	0.06	–	V
tfilt_OV_VR1	VR1 overvoltage filter time		–	15	–	μs
toff_VR1	VR1 off time after TSD		–	1.0	–	s

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ELECTRICAL CHARACTERISTICS (continued)

6 V ≤ VS ≤ 18 V; -40°C ≤ Tj ≤ 150°C; 4.75 V ≤ VR1 ≤ 5.25 V; RLT = 60 Ω, CLT = 100 pF, CST not used, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
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VR1 VOLTAGE REGULATOR

Is_add_VR1	VS consumption adder of VR1	(Note 7)	–	0.01 x I(VR1)	–	A
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CAN BUS LINES (Pins CANH and CANL)

I _{o(rec)}	Recessive output current at pins CANH and CANL	CAN enabled; -27 V < V _{CANH} , V _{CANL} < 32 V	-5.0	–	5.0	mA
I _{LI}	Input leakage current	0 Ω ≤ R(VR1 to GND) < 1 MΩ; V _{CANH} = V _{CANL} = 5 V	-5.0	0	5.0	μA
V _{o(rec)} (CANH)	Recessive output voltage at pin CANH	CAN enabled; TxDC = High; no load	2.0	2.5	3.0	V
V _{o(rec)} (CANL)	Recessive output voltage at pin CANL	CAN enabled; TxDC = High; no load	2.0	2.5	3.0	V
V _{o(off)} (CANH)	Recessive output voltage at pin CANH	CAN disabled; no load	-0.1	0	0.1	V
V _{o(off)} (CANL)	Recessive output voltage at pin CANL	CAN disabled; no load	-0.1	0	0.1	V
V _{o(off)} (diff)	Differential bus output voltage in off mode (V _{CANH} - V _{CANL})	CAN disabled; no load	-0.2	0	0.2	V
V _{o(dom)} (CANH)	Dominant output voltage at pin CANH	CAN enabled; 50 Ω ≤ R _{LT} ≤ 65 Ω; TxDC = Low; t < t _{dom} (TxDC)	2.75	3.5	4.5	V
V _{o(dom)} (CANL)	Dominant output voltage at pin CANL	CAN enabled; 50 Ω ≤ R _{LT} ≤ 65 Ω; TxDC = Low; t < t _{dom} (TxDC)	0.5	1.5	2.25	V
V _{o(sym)}	Driver output voltage symmetry (V _{CANH} + V _{CANL})	CAN enabled; CST = 4.7 nF; TxDC driven by square wave up to 1 MHz	0.9	–	1.1	VR1
V _{o(dom)} (diff)	Differential bus output voltage (V _{CANH} - V _{CANL})	CAN enabled; 45 Ω ≤ R _{LT} ≤ 65 Ω; TxDC = Low; dominant	1.5	2.25	3.0	V
V _{o(dom)} (diff)_arb	Differential bus output voltage during arbitration (V _{CANH} - V _{CANL})	CAN enabled; R _{LT} = 2240 Ω; TxDC = Low; dominant; (Note 7)	1.5	–	5.0	V
V _{o(rec)} (diff)	Differential bus output voltage (V _{CANH} - V _{CANL})	CAN enabled; no load; V _{TxDC} = High; recessive	-50	0	50	mV
I _{o(sc)} (CANH)	Short circuit output current at pin CANH	CAN enabled; TxDC = Low; V _{CANH} = -3 V -3 V ≤ V _{CANH} ≤ 18 V	-100 -100	-70	-40 2.0	mA
I _{o(sc)} (CANL)	Short circuit output current at pin CANL	CAN enabled; TxDC = Low; V _{CANL} = 36 V -3 V ≤ V _{CANL} ≤ 18 V	40 -1.5	70	100 100	mA
V _{i(rec)} (diff)_NM	Differential input voltage range recessive state	CAN enabled; no load; -12 V ≤ V _{CANH} , V _{CANL} ≤ 12 V	3.0	–	0.5	V
V _{i(rec)} (diff)_LP		CAN disabled; no load; -12 V ≤ V _{CANH} , V _{CANL} ≤ 12 V	-3.0	–	0.4	V
V _{i(dom)} (diff)_NM	Differential input voltage range dominant state	CAN enabled; no load; -12 V ≤ V _{CANH} , V _{CANL} ≤ 12 V	0.9	–	8.0	V
V _{i(dom)} (diff)_LP		CAN disabled; no load; -12 V ≤ V _{CANH} , V _{CANL} ≤ 12 V	1.05	–	8.0	V
V _{i(diff)} (th)_NM	Differential receiver threshold voltage in normal mode	CAN enabled; -12 V ≤ V _{CANH} , V _{CANL} ≤ 12 V	0.5	–	0.9	V
V _{i(diff)} (th)_LP	Differential receiver threshold voltage in wake-up-detection mode	CAN disabled; -12 V ≤ V _{CANH} , V _{CANL} ≤ 12 V	0.4	–	1.05	V

ELECTRICAL CHARACTERISTICS (continued)

6 V ≤ VS ≤ 18 V; -40°C ≤ TJ ≤ 150°C; 4.75 V ≤ VR1 ≤ 5.25 V; RLT = 60 Ω, CLT = 100 pF, CST not used, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
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CAN BUS LINES (Pins CANH and CANL)

R _{i(cm)} (CANH)	Common-mode input resistance at pin CANH	-2 V ≤ V _{CANH} , V _{CANL} ≤ 7 V	15	25	37	kΩ
R _{i(cm)} (CANL)	Common-mode input resistance at pin CANL	-2 V ≤ V _{CANH} , V _{CANL} ≤ 7 V	15	25	37	kΩ
R _{i(cm)} (m)	Matching between pin CANH and pin CANL common mode input resistance	V _{CANH} = V _{CANL} = 5 V	-1.0	0	1.0	%
R _{i(diff)}	Differential input resistance		25	50	75	kΩ
C _i (CANH)	Input capacitance at pin CANH	TxDC = High; (Note 7)	–	7.5	20	pF
C _i (CANL)	Input capacitance at pin CANL	TxDC = High; (Note 7)	–	7.5	20	pF
C _i (diff)	Differential input capacitance	TxDC = High; (Note 7)	–	3.75	10	pF

TIMING CHARACTERISTICS (see Figure 3, Figure 4 and Figure 5)

t _d (TxDC-BUSon)	Propagation delay TxDC to bus active	CAN enabled	–	65	–	ns
t _d (TxDC-BUSoff)	Propagation delay TxDC to bus inactive	CAN enabled	–	90	–	ns
t _d (BUSon-RxDC)	Propagation delay bus active to RxDC	CAN enabled	–	60	–	ns
t _d (BUSoff-RxDC)	Propagation delay bus inactive to RxDC	CAN enabled	–	65	–	ns
t _{pd_dr}	Propagation delay TxDC to RxDC dominant to recessive transition	CAN enabled	50	100	170	ns
t _{pd_rd}	Propagation delay TxDC to RxDC recessive to dominant transition	CAN enabled	50	120	170	ns
t _{wake_filt}	Dominant time for wake-up via bus	CAN_EN = Low	0.15	–	1.8	μs
t _{dwakerd}	Delay to flag wake event (recessive to dominant transitions)	CAN_EN = Low; Valid bus wake-up event	0.5	–	6.0	μs
t _{dwakedr}	Delay to flag wake event (dominant to recessive transitions)	CAN_EN = Low; Valid bus wake-up event	0.5	–	6.0	μs
t _{wake_to}	Bus time for wake-up time-out	CAN_EN = Low	1.0	–	10	ms
t _{dom} (TxDC)	TxDC dominant time for time-out	CAN_EN = High; TxDC = Low	1.0	–	10	ms
t _{Bit} (RxDC)	Bit time on RxDC pin	t _{Bit} (TxDC) = 500 ns	400	–	550	ns
		t _{Bit} (TxDC) = 200 ns	120	–	220	ns
t _{Bit} (Vi(diff))	Bit time on bus pins (CANH – CANL)	t _{Bit} (TxDC) = 500 ns	435	–	530	ns
		t _{Bit} (TxDC) = 200 ns	155	–	210	ns
Δt _{Rec}	Receiver timing symmetry Δt _{Rec} = t _{Bit} (RxDC) – t _{Bit} (Vi(diff))	t _{Bit} (TxDC) = 500 ns	-65	–	40	ns
		t _{Bit} (TxDC) = 200 ns	-45	–	15	ns

ELECTRICAL CHARACTERISTICS (continued)

6 V ≤ V_S ≤ 18 V; -40°C ≤ T_j ≤ 150°C; 4.75 V ≤ V_{R1} ≤ 5.25 V; R_{LT} = 60 Ω, C_{LT} = 100 pF, C_{ST} not used, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
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TIMING CHARACTERISTICS (see Figure 3, Figure 4 and Figure 5)

t _{d(LP-NM)}	Mode change delay from wake-up detection to normal mode	CAN_EN = Low → High	–	25	47	μs
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WATCHDOG TIMING

twd_acc	Watchdog timing accuracy		-15	–	15	%
t_wd_TO	Timeout watchdog period	After WD_EN low → high transition or RSTN pulse	56	65	74	ms
t_wd_CW	Window watchdog closed window		5.1	6.0	6.9	ms
t_wd_OW	Window watchdog open window		85	100	115	ms
t_WDI	Minimum WDI pulse width accepted as a watchdog service		6.0	–	–	μs

WAKE INPUT

V _{th_WAKE}	WAKE pin threshold		2.0	–	4.0	V
V _{hys_WAKE}	WAKE pin threshold hysteresis		0.1	–	0.7	V
t _{filt_WAKE}	WAKE wake-up filter time		10	–	50	μs
I _{pu_WAKE}	Pull-up current on WAKE pin	V(WAKE) = 4 V	-11	–	-3.0	μA
I _{pd_WAKE}	Pull-down current on WAKE pin	V(WAKE) = 2 V	3.0	–	11	μA

DIGITAL OUTPUTS, RxD, WAKE_OUT

I _{outL_pinx}	Low-level output driving current	pinx is logical Low, forced V(pinx) = 0.4 V	1.0	6.0	12	mA
I _{outH_pinx}	High-level output driving current	pinx is logical High, forced V(pinx) = V _{R1} – 0.4 V	-8.0	-3.0	-1.0	mA

DIGITAL OUTPUT RSTN

I _{outL_RSTN}	Low-level output driving current	RSTN is active (logical Low), forced V(RSTN) = 0.4 V	2.0	5.0	12	mA
V _{outL_RSTN}	Low-level output voltage, low V _{R1} /V _S	V _{R1} > 4.7 V, I(RSTN) = 0.6 mA	–	0.2	0.4	V
		V _{R1} > 2 V, V _S < V _{R1} , I(RSTN) = 0.1 mA	–	0.2	0.4	
		V _{R1} = 0 V, V _S > 2 V, I(RSTN) = 0.2 mA	–	0.2	0.4	
R _{pu_RSTN}	Internal pull-up resistor to V _{R1}		5.0	10.0	19	kΩ
t_RSTN	Reset pulse length after V _{R1} undervoltage or watchdog failure		6.8	8.0	9.2	kΩ

DIGITAL INPUTS TxD, CAN_EN, WD_EN, WDI

V _{inL_pinx}	Low-level input voltage (logical "Low")		–	–	0.8	V
V _{inH_pinx}	High-level input voltage (logical "High")		2.0	–	–	V
V _{in_hys_pinx}	Input voltage hysteresis		–	200	–	mV
R _{pu_pinx}	Internal pull-up resistor to V _{R1} ; pin TxD		55	100	185	kΩ
R _{pd_pinx}	Internal pull-down resistor to ground; pins CAN_EN, WDI		55	100	185	kΩ
I _{pu_WD_EN}	Internal pull-up current to V _{R1} , pin WD_EN	V(WD_EN) = 0 V, pull-up current source active	50	100	200	μA
t _{per_pu_WDEN}	WD_EN pull-up current source activation period	WD_EN = CAN_EN = Low	–	610	–	μs

ELECTRICAL CHARACTERISTICS (continued)

6 V ≤ VS ≤ 18 V; -40°C ≤ Tj ≤ 150°C; 4.75 V ≤ VR1 ≤ 5.25 V; RLT = 60 Ω, CLT = 100 pF, CST not used, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
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DIGITAL INPUTS TxDC, CAN_EN, WD_EN, WDI

ton_pu_WDEN	WD_EN pull-up current source activation on-time	WD_EN = CAN_EN = Low	-	5.0	-	μs
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THERMAL PROTECTION

Tsd	Thermal shutdown level	Temperature increasing	155	165	175	°C
Tsd_hys	Thermal shutdown level hysteresis	Temperature decreasing	-	10	-	°C

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

7. Not tested in production, guaranteed by design.

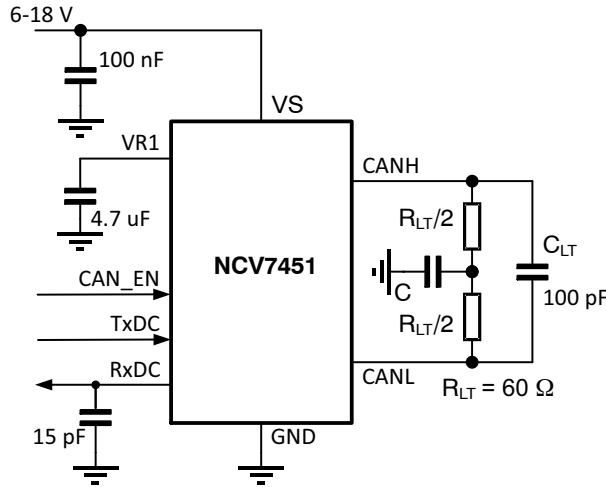
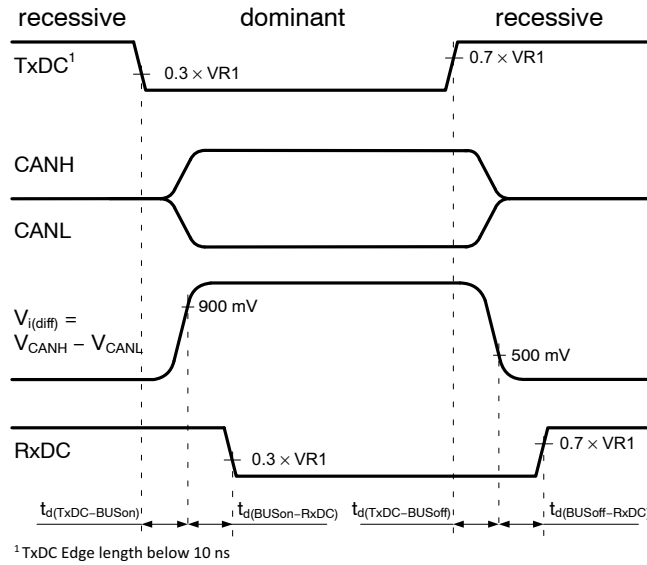


Figure 3. Test Circuit for CAN Timing Characteristics



¹ TxDC Edge length below 10 ns

Figure 4. CAN Transceiver Timing Diagram – Propagation Delays

NCV7451

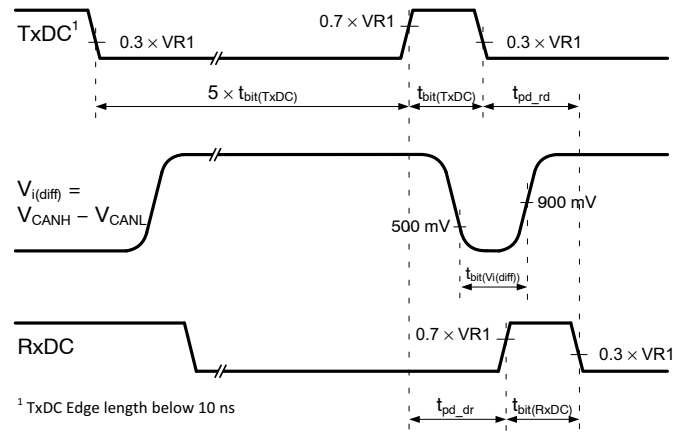


Figure 5. CAN Transceiver Timing Diagram – Loop Delay and Recessive Bit Time

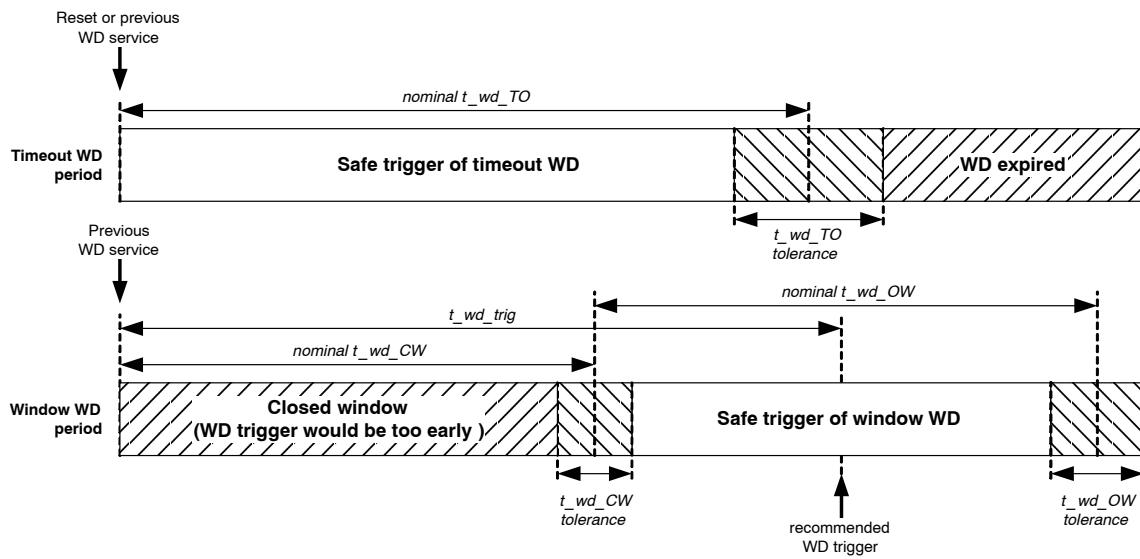


Figure 6. Watchdog Modes Timing

FUNCTIONAL DESCRIPTION

Supply Concept

The device has one battery supply pin VS, supplying the VR1 regulator and logic control. The supply line has to be properly decoupled by filtering capacitors close to the device pin.

VR1 Low-drop Regulator

VR1 is a low-drop output regulator providing 5 V voltage derived from the VS main supply. It is able to deliver up to 250 mA and is primarily intended to supply the on-chip CAN transceiver, the application microcontroller unit (MCU) and related 5 V loads (e.g. its own MCU-related digital inputs/outputs). An external capacitor needs to be connected on VR1 pin in order to ensure the regulator's stability and to filter the disturbances caused by the connected loads.

VR1 voltage supplies all the digital low-voltage input/output pins.

The protection and monitoring of the VR1 regulator consist of the following features:

- ◆ VR1 Current Limitation – the two-level current limitation controlled by VR1 reset comparator to reduce the power dissipation in case of shorts to ground by the current fold-back (see Figure 7)
- ◆ VR1 Reset Comparator – the VR1 regulator output is compared with a reset level RES_VR1 . If the VR1

level drops below this level for longer than $t_{filt_RES_VR1}$, a reset towards the MCU is generated through the RSTN pin and the CAN transceiver is disabled.

- ◆ VR1 Overvoltage Reset Comparator – the VR1 regulator output is compared with an overvoltage level OV_VR1 . If the VR1 level crosses this threshold for longer than $t_{filt_OV_VR1}$, a reset towards the MCU is generated through the RSTN pin and the CAN transceiver is disabled.
- ◆ Temperature (see Figure 14)

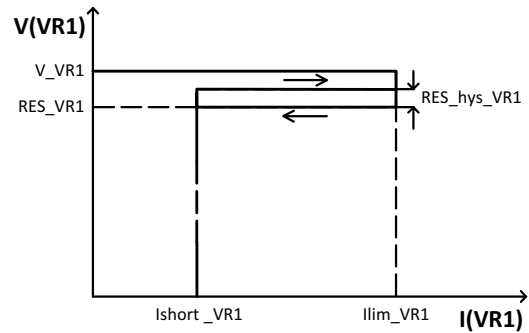


Figure 7. VR1 Current Fold-back

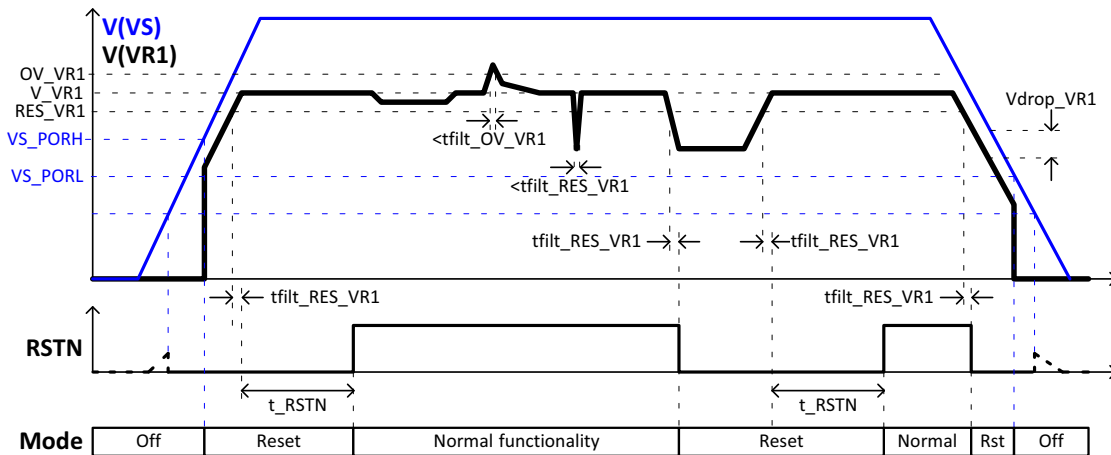


Figure 8. VS1 and VR1 Monitoring

CAN Transceiver

The SBC contains one high-speed CAN transceiver compliant with ISO11898-2:2016. The transceiver consists of the following sub-blocks: transmitter, receiver, and wake-up detector.

If enabled ($CAN_EN = High$), the CAN transceiver is ready to provide the full-speed interface between the bus and a CAN controller connected on pins RxDC (received data) and TxDC (data to transmit).

In order to prevent a faulty node from blocking the bus traffic, the maximum length of the transmitted dominant symbol is limited by a time-out counter to $t_{dom}(TxDC)$. In case the TxDC Low signal exceeds the timeout value, the transmitter returns automatically to the recessive state. The transmission is again de-blocked when TxDC pin returns to high (recessive) state.

If the CAN block is disabled ($CAN_EN = Low$) or RSTN pin active (Low) due to failed watchdog service or VR1

undervoltage / overvoltage, the CAN transceiver is in its wake-up detection state. Logical level on TxDC is ignored and pin RxDC is kept high until a CAN bus wake-up is detected. The CAN bus wake-up corresponds to a pattern consisting of dominant – recessive – dominant symbols of at least t_{wake_filt} each. The RxDC starts following the CAN bus afterwards. The pattern must be received within t_{wake_to} to be recognized as a valid wake-up event, otherwise internal wake-up logic is reset.

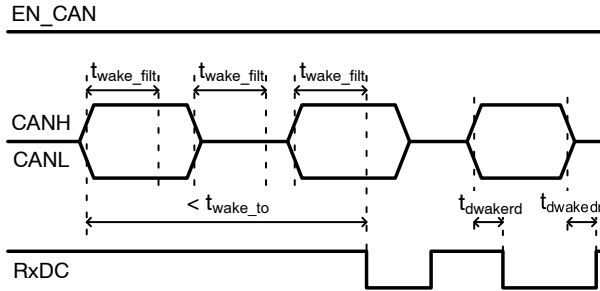


Figure 9. CAN Wake-up Pattern

WAKE Comparator

WAKE pin is a high-voltage input typically used to monitor an external contact or switch. The inverted logical level on pin WAKE can be polled via WAKE_OUT output push-pull pin.

A stable logical level of the WAKE signal is ensured even without an external connection:

- if the WAKE level is High for longer than t_{filt_WAKE} , an internal pull-up current source is connected to WAKE pin

- if the WAKE level stays Low for longer than t_{filt_WAKE} , an internal pull-down current source is connected to WAKE pin

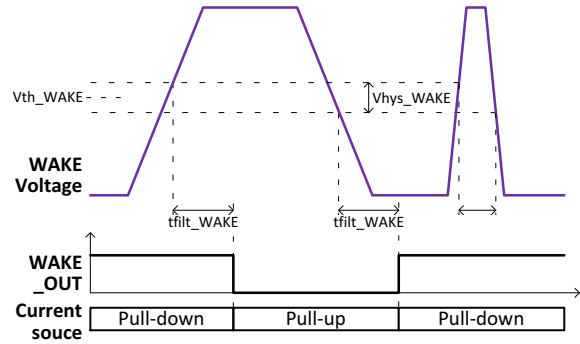


Figure 10. WAKE Pin Functionality

Watchdog

The on-chip watchdog requires that the MCU software “triggers” or “services” the watchdog in a specified time frame. A correct watchdog service consists of high-to-low transition on the WDI input. The watchdog timer re-starts immediately after a successful trigger is received.

After any Reset event (power-up, watchdog failure, VR1 under-/overvoltage, thermal shutdown) or watchdog enable (WD_EN = Low → High), the watchdog always starts in a timeout mode. The MCU software must serve the watchdog any time before the time-out expiration. After the watchdog is triggered for the first time, it starts working in a window mode operation: the watchdog time is split to two distinct parts – a closed window, where the watchdog may not be triggered, is followed by an open window where the MCU must send a valid watchdog trigger (see Figure 12).

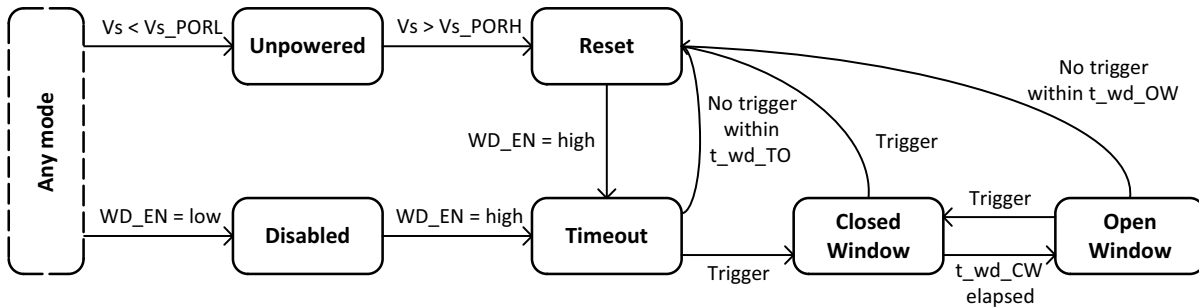


Figure 11. Watchdog Operating Modes

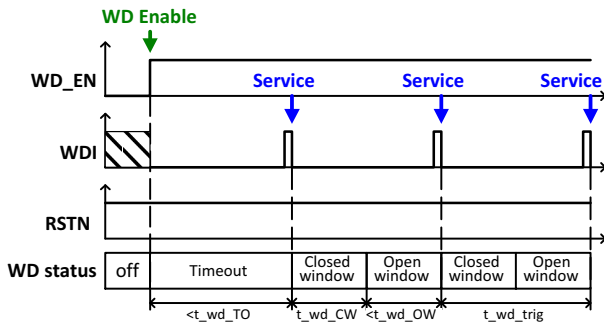


Figure 12. Correct Watchdog Services

In case the watchdog is not triggered before the timeout or open window elapses (Figure 13, Figure 14), or trigger is sent within the closed window (Figure 15), RSTN signal is generated and then watchdog restarted in the timeout mode again.

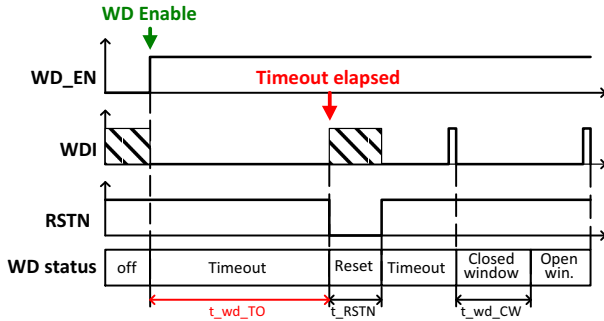


Figure 13. Missed Watchdog in Timeout Mode

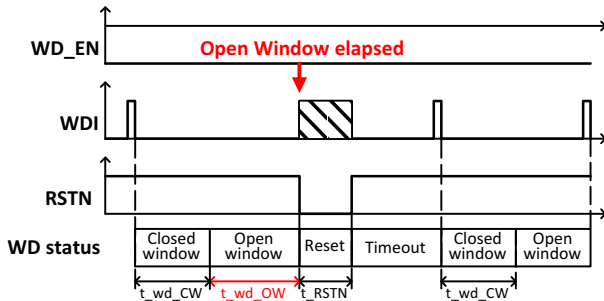


Figure 14. Missed Watchdog in Window Mode

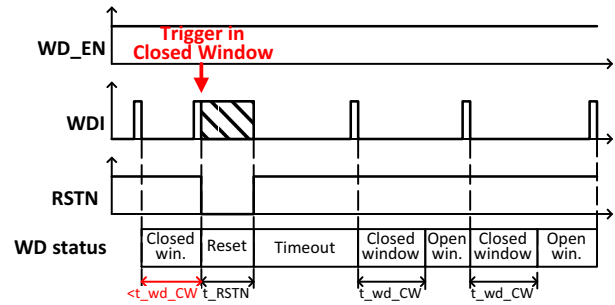


Figure 15. Watchdog Service during Closed Window

The WD_EN pin has an integrated pull-up source to enable the watchdog in case the pin is disconnected from the application. To reduce the power consumption in the low-power mode (watchdog and CAN disabled), the WD_EN pull-up current source is switched on for ton_pu_WDEN time with period of $tper_pu_WDEN$. The pin state is sampled in the end of the current source activation. Once High level is detected on the WD_EN pin, the current source is activated permanently.

To ensure the High level is correctly detected if the pin becomes floating, external WD_EN capacitance should stay below 50 pF.

After the rising edge on WD_EN pin, the MCU should wait $tper_pu_WDEN$ before the first watchdog service.

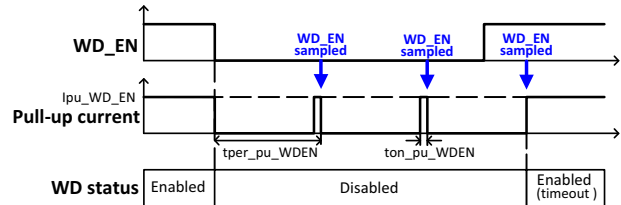


Figure 16. WD_EN Pull-up Current Source Activation

Thermal Protection

A thermal protection circuit protects the IC from damage by complete device de-activation if the junction temperature exceeds a value of Tsd .

The device recovers automatically after the junction temperature drops below Tsd level lowered by hysteresis Tsd_hys and $toff_VR1$ (typ. 1 second) expires.

Operating Modes

The device operating modes are directly controlled by CAN_EN input pin and failure events (see Figure 17).

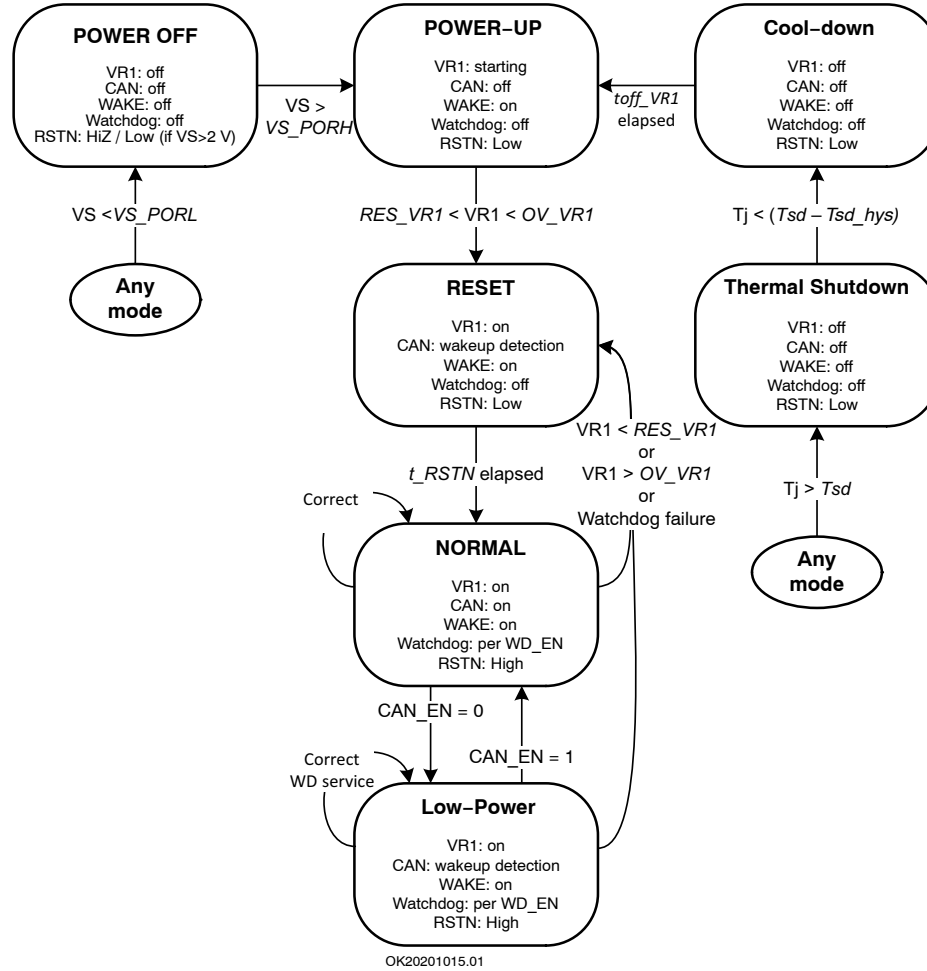


Figure 17. Operating Modes Diagram

ISO11898-2:2016 PARAMETER CROSS-REFERENCE TABLE

ISO 11898-2:2016 Specification		NCV7451 Datasheet
Parameter	Notation	Symbol
DOMINANT OUTPUT CHARACTERISTICS		
Single ended voltage on CAN_H	V_{CAN_H}	$V_{o(dom)}(CANH)$
Single ended voltage on CAN_L	V_{CAN_L}	$V_{o(dom)}(CANL)$
Differential voltage on normal bus load	V_{Diff}	$V_{o(dom)}(diff)$
Differential voltage on effective resistance during arbitration	V_{Diff}	$V_{o(dom)}(diff_arb)$
Differential voltage on extended bus load range (optional)	V_{Diff}	NA
DRIVER SYMMETRY		
Driver symmetry	V_{SYM}	$V_{o(sym)}$
DRIVER OUTPUT CURRENT		
Absolute current on CAN_H	I_{CAN_H}	$I_{o(SC)}(CANH)$
Absolute current on CAN_L	I_{CAN_L}	$I_{o(SC)}(CANL)$
RECEIVER OUTPUT CHARACTERISTICS, BUS BIASING ACTIVE		
Single ended output voltage on CAN_H	V_{CAN_H}	$V_{o(rec)}(CANH)$
Single ended output voltage on CAN_L	V_{CAN_L}	$V_{o(rec)}(CANL)$
Differential output voltage	V_{Diff}	$V_{o(rec)}(diff)$
RECEIVER OUTPUT CHARACTERISTICS, BUS BIASING INACTIVE		
Single ended output voltage on CAN_H	V_{CAN_H}	$V_{o(off)}(CANH)$
Single ended output voltage on CAN_L	V_{CAN_L}	$V_{o(off)}(CANL)$
Differential output voltage	V_{Diff}	$V_{o(off)}(dif)$
TRANSMIT DOMINANT TIMEOUT		
Transmit dominant timeout, long	t_{dom}	$t_{dom}(TxDC)$
Transmit dominant timeout, short	t_{dom}	NA
STATIC RECEIVER INPUT CHARACTERISTICS, BUS BIASING ACTIVE		
Recessive state differential input voltage range	V_{Diff}	$V_{i(rec)}(diff)_NM$
Dominant state differential input voltage range	V_{Diff}	$V_{i(dom)}(diff)_NM$
STATIC RECEIVER INPUT CHARACTERISTICS, BUS BIASING INACTIVE		
Recessive state differential input voltage range	V_{Diff}	$V_{i(rec)}(diff)_LP$
Dominant state differential input voltage range	V_{Diff}	$V_{i(dom)}(diff)_LP$
RECEIVER INPUT RESISTANCE		
Differential internal resistance	R_{Diff}	$R_{i(diff)}$
Single ended internal resistance	R_{CAN_H} R_{CAN_L}	$R_{i(cm)}(CANH)$ $R_{i(cm)}(CANL)$
RECEIVER INPUT RESISTANCE MATCHING		
Matching a of internal resistance	m_R	$R_{i(cm)}(m)$
IMPLEMENTATION LOOP DELAY REQUIREMENT		
Loop delay	t_{Loop}	t_{pd_rd} t_{pd_dr}
DATA SIGNAL TIMING REQUIREMENTS for use with bit rates above 1 Mbit/s and up to 2 Mbit/s		
Transmitted recessive bit width @ 2 Mbit/s	$t_{Bit}(Bus)$	$t_{Bit}(Vi(diff))$
Received recessive bit width @ 2 Mbit/s	$t_{Bit}(RXD)$	$t_{Bit}(RxDC)$
Receiver timing symmetry @ 2 Mbit/s	Δt_{Rec}	Δt_{Rec}

NCV7451

ISO11898-2:2016 PARAMETER CROSS-REFERENCE TABLE (continued)

ISO 11898-2:2016 Specification		NCV7451 Datasheet
Parameter	Notation	Symbol
DATA SIGNAL TIMING REQUIREMENTS for use with bit rates above 2 Mbit/s and up to 5 Mbit/s		
Transmitted recessive bit width @ 5 Mbit/s	$t_{\text{Bit(Bus)}}$	$t_{\text{Bit}(V_i(\text{diff}))}$
Transmitted recessive bit width @ 5 Mbit/s	$t_{\text{Bit(RXD)}}$	$t_{\text{Bit(RxDC)}}$
Received recessive bit width @ 5 Mbit/s	Δt_{Rec}	Δt_{Rec}
MAXIMUM RATINGS OF $V_{\text{CAN_H}}$, $V_{\text{CAN_L}}$ AND V_{DIFF}		
Maximum rating V_{Diff}	V_{Diff}	V_{diff}
General maximum rating $V_{\text{CAN_H}}$ and $V_{\text{CAN_L}}$	$V_{\text{CAN_H}}$ $V_{\text{CAN_L}}$	CANH CANL
Optional: Extended maximum rating $V_{\text{CAN_H}}$ and $V_{\text{CAN_L}}$	$V_{\text{CAN_H}}$ $V_{\text{CAN_L}}$	NA
MAXIMUM LEAKAGE CURRENTS ON CAN_H AND CAN_L, UNPOWERED		
Leakage current on CAN_H, CAN_L	$I_{\text{CAN_H}}$, $I_{\text{CAN_L}}$	I_{LI}
BUS BIASING CONTROL TIMINGS		
CAN activity filter time, long	t_{Filter}	NA
CAN activity filter time, short	t_{Filter}	$t_{\text{wake_filt}}$
Optional: Wake-up timeout, short	t_{Wake}	NA
Optional: Wake-up timeout, long	t_{Wake}	$t_{\text{wake_to}}$
Timeout for bus inactivity (Required for selective wake-up implementation only)	t_{Silence}	NA
Bus Bias reaction time (Required for selective wake-up implementation only)	t_{Bias}	NA

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